



Product data sheet

1. Product profile

1.1 General description

 $V_{RRM} \le 400 V$

■ $I_{TSM} \le 8 \text{ A} (t = 10 \text{ ms})$

Passivated ultra sensitive gate thyristor in a SOT54 plastic package.

1.2 Features

	 Ultra sensitive gate 	Direct interfacing to low power gate trigger circuits
1.3	Applications	
	 Earth leakage circuit breakers or Ground Fault Circuit Interrupters (GFCI) 	General purpose switching
	Solid state relays	Small engine ignition
1.4	Quick reference data	
	■ V _{DRM} ≤ 400 V	$I_{T(RMS)} \le 0.8 \text{ A}$

2. Pinning information

Pin	Description	Simplified outline	Graphic symbol
1	anode (A)		
2	gate (G)		A H K
3	cathode (K)		G sym037
		SOT54 (TO-92)	

 $\blacksquare I_{GT} \le 12 \ \mu A$



3. Ordering information

Table 2. Ordering information						
Type number	Package					
	Name	Description	Version			
EC103D1	TO-92	plastic single-ended leaded (through hole) package; 3 leads	SOT54			

4. Limiting values

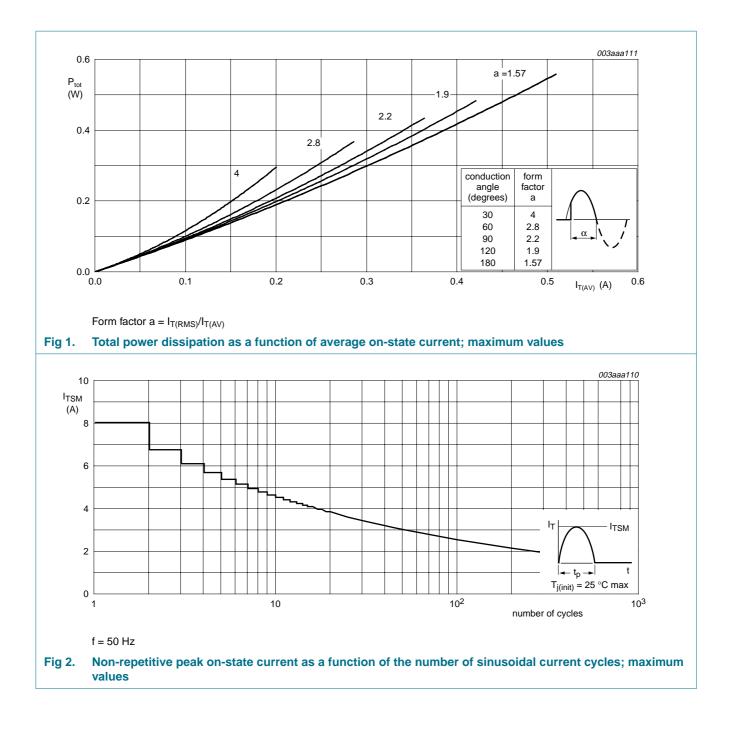
Table 3. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

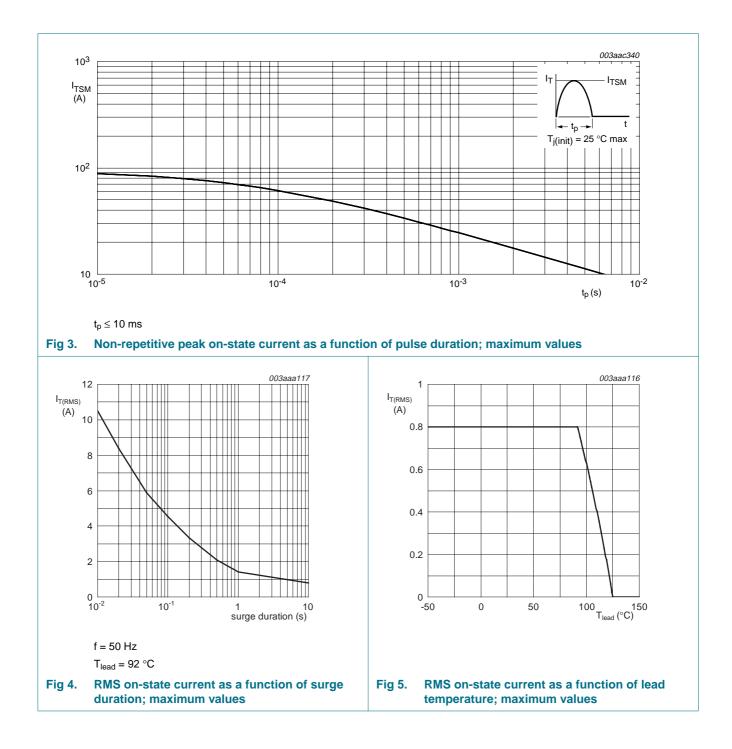
Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	400	V
V _{RRM}	repetitive peak reverse voltage		-	400	V
V _{DSM}	non-repetitive peak off-state voltage		-	450	V
V _{RSM}	non-repetitive peak reverse voltage		-	450	V
I _{T(AV)}	average on-state current	half sine wave; T _{lead} ≤ 92 °C; see <u>Figure 1</u>	-	0.5	А
I _{T(RMS)}	RMS on-state current	all conduction angles; see <u>Figure 4</u> and <u>5</u>	-	0.8	А
I _{TSM}	non-repetitive peak on-state current	half sine wave; $T_j = 25 \text{ °C prior to}$ surge; see <u>Figure 2</u> and <u>3</u>			
		t = 10 ms	-	8	А
		t = 8.3 ms	-	9	А
l ² t	I ² t for fusing	t _p = 10 ms	-	0.32	A ² s
dl _T /dt	rate of rise of on-state current	$I_{TM} = 2 \text{ A}; I_G = 10 \text{ mA};$ $dI_G/dt = 0.1 \text{ A}/\mu\text{s}$	-	50	A/μs
I _{GM}	peak gate current		-	1	А
V _{RGM}	peak reverse gate voltage		-	5	V
P _{GM}	peak gate power		-	2	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.1	W
T _{stg}	storage temperature		-40	+150	°C
Tj	junction temperature		-	125	°C

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Thyristor, sensitive gate

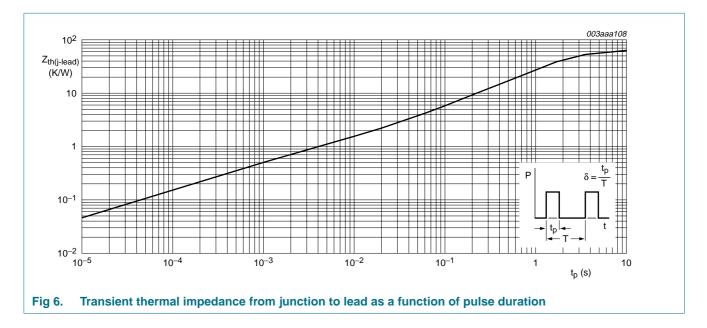


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Thermal characteristics 5.

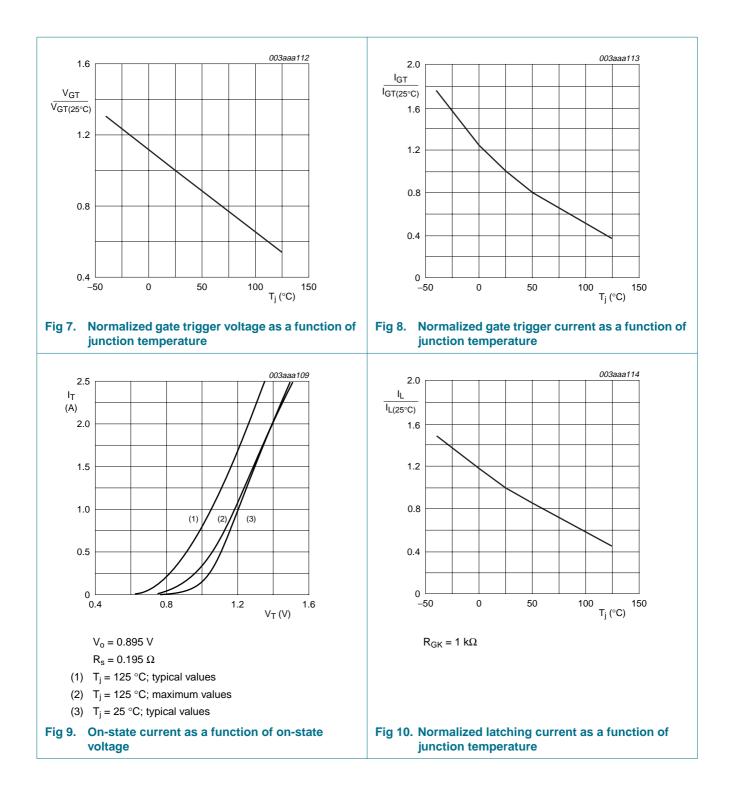
Table 4.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-lead)}$	thermal resistance from junction to lead	see Figure 6	-	-	60	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	printed-circuit board mounted; lead length 4 mm	-	150	-	K/W

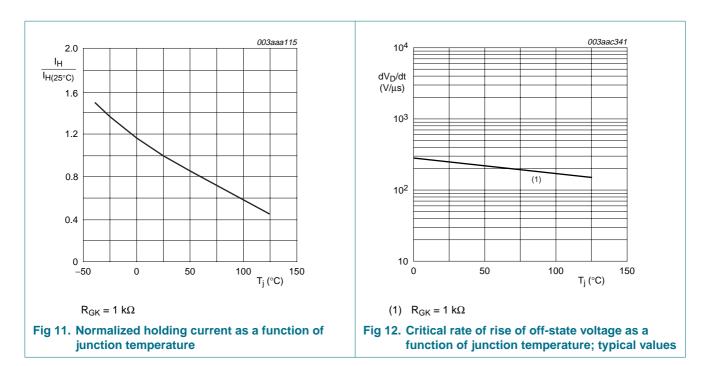


6. Characteristics

Table 5. <i>T_j = 25</i> ° <i>C</i>	Characteristics unless otherwise stated.					
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
Static cha	racteristics					
I _{GT}	gate trigger current	$V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ see } \frac{\text{Figure 8}}{100000000000000000000000000000000000$	-	3	12	μA
lL	latching current	V_D = 12 V; I _{GT} = 0.5 mA; R _{GK} = 1 k Ω ; see Figure 10	-	2	6	mA
I _H	holding current	V_D = 12 V; I _{GT} = 0.5 mA; R _{GK} = 1 k Ω ; see <u>Figure 11</u>	-	2	5	mA
VT	on-state voltage	$I_T = 1 A$	-	1.2	1.35	V
V _{GT}	gate trigger voltage	I _T = 10 mA; see <u>Figure 7</u>				
		V _D = 12 V	-	0.5	0.8	V
		$V_D = V_{DRM(max)}; T_j = 125 \ ^{\circ}C$	0.2	0.3	-	V
ID	off-state current		-	0.05	0.1	mA
I _R	reverse current		-	0.05	0.1	mA
Dynamic of	characteristics					
dV _D /dt	rate of rise of off-state voltage	$ V_{DM} = 0.67 \times V_{DRM(max)}; T_j = 125 \ ^\circ C; \\ exponential waveform; R_{GK} = 1 \ k\Omega; \\ see \ \underline{Figure \ 12} $	-	150	-	V/µs
t _{gt}	gate-controlled turn-on time	$\begin{split} I_{TM} = 2 \text{ A}; V_D = V_{DRM(max)}; I_G = 10 \text{mA}; \\ dI_G/dt = 0.1 A/\mu \text{s} \end{split}$	-	2	-	μs
t _q	commutated turn-off time	$ \begin{split} &V_{DM} = 0.67 \times V_{DRM(max)}; \ T_{j} = 125 \ ^{\circ}C; \\ &I_{TM} = 1.6 \ A; \ V_{R} = 35 \ V; \\ &(dI_{T}/dt)_{M} = 30 \ A/\mu s; \ dV_{D}/dt = 2 \ V/\mu s; \\ &R_{GK} = 1 \ k\Omega \end{split} $	-	100	-	μs

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7. Package information

Epoxy meets requirements of UL 94 V-0 at 3.175 mm

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8. Package outline

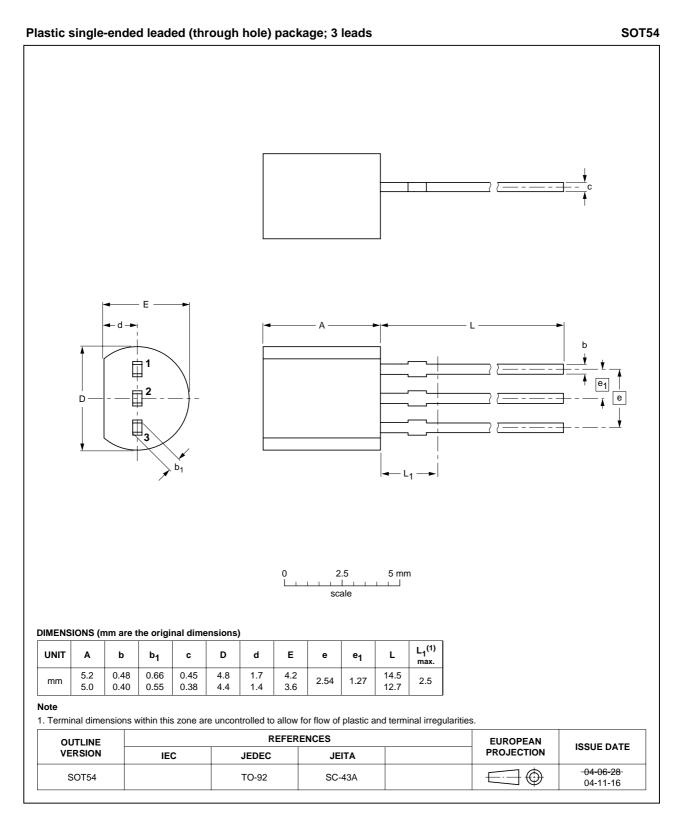


Fig 13. Package outline SOT54 (TO-92)

9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
EC103D1_2	20080731	Product data sheet	-	EC103D1-01		
Modifications:		 The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. 				
	 Legal texts have been adapted to the new company name where appropriate. 					
	 Table 3 "Limiting values" on page 2; V_{DSM} and V_{RSM} added. 					
	 Table 5 "Characteristics" on page 6; dV_D/dt uprated. 					
	 Figure 4 on page 4; graph redrawn. 					
	• Figure 6 on page 5; graph redrawn.					
	• Figure 11; graph added.					
	• Figure 12; graph added.					
EC103D1-01 (9397 750 08574)	20011101	Product data	-	-		

10. Legal information

10.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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